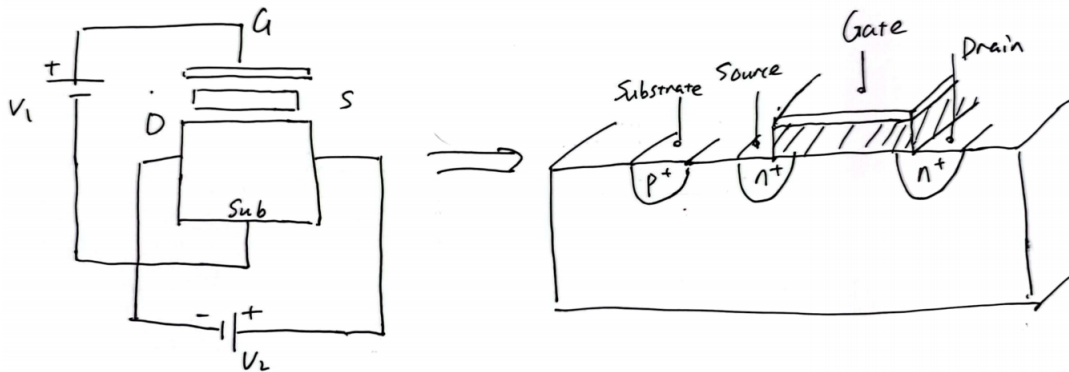


Introduction to MOSFETs

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How the MOSFET Come



The origin of the three-dimensional diagram of the MOSFET

When V_1 is added to both ends of a capacitor, electrons accumulate on the lower plate; after V_2 is added to both ends of the lower plate, the electrons start to move under the action of the electric field, forming a current. This is the simplest MOSFET model. We cannot operate the side of the wafer, so we extend the two ends of the lower plate to the front. Then it comes to a three-dimensional diagram of the MOSFET.

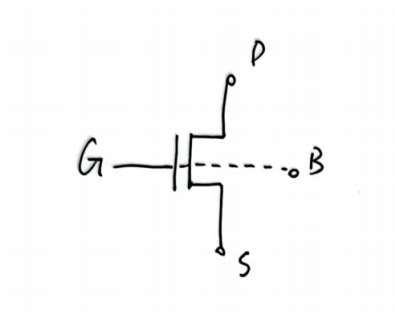
The full name of MOSFET is Metal Oxide Semiconductor Field Effect Transistor. Metal refers to the electrode of the gate, with an insulating layer of silicon dioxide underneath.

Therefore, the current flowing from the gate can be almost ignored.

The smaller the thickness of the insulating layer, the larger the capacitance, the more electrons are attracted, and the larger I_D is.

Flip the model, we get the circuit symbol of MOSFET.

The Source and the Drain are symmetrical. We can't tell which is which. The Substrate can be anywhere.



Circuit symbol of MOSFET

The level of the Substrate (or Bulk) is usually given, so its symbol is generally not marked

MOS Operation

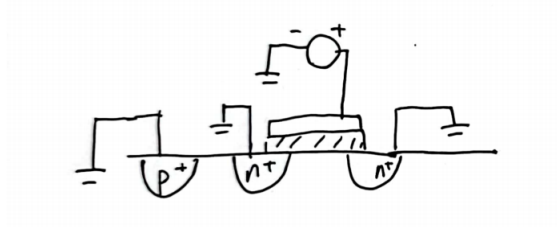
V_{th} : The voltage at which we introduce electrons instead of the negative ions.

Depletion: Deplete the holes.

Now let us start to learn some operation about MOSFET.

$$V_D = V_S = 0$$

We begin at applying voltage to the Gate and connect the Source and the Drain to the ground.

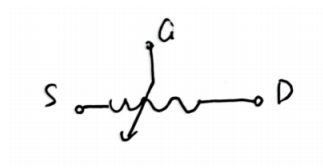


Apply voltage to the Gate

When the V_G increase, the attraction of the Gate increase.

When the $V_G = V_{th}$, A channel appears between two n-type semiconductors and begins to conduct electricity.

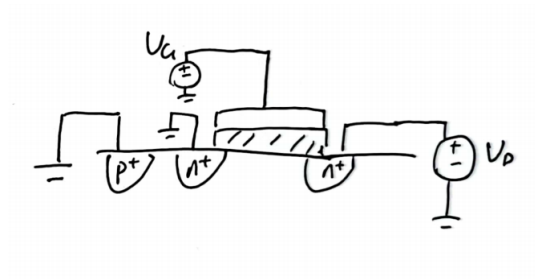
When the $V_G > V_{th}$, the MOSFET becomes a voltage controlled resistor.



Voltage controlled resistor

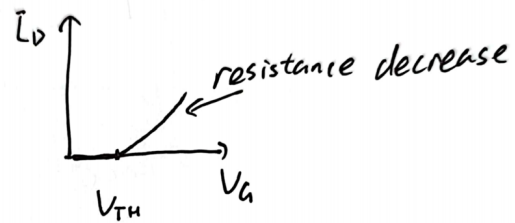
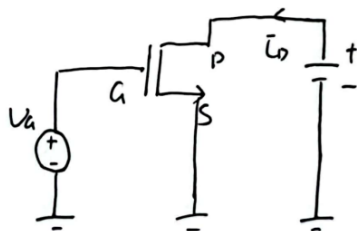
$$V_D > V_S = 0$$

Then we add voltage to the Drain.



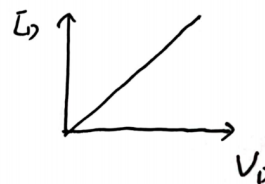
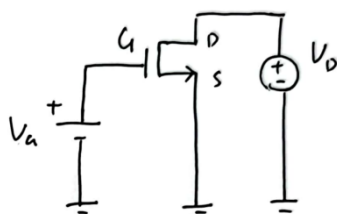
Apply voltage to the Gate and the Drain

The control variable method is very commonly used in Teacher Razavi's class. We consider $V_D = \text{constant}$ first.



$$V_D = \text{constant, e.g. } 0.3V$$

Then we consider $V_G = \text{constant}$.



$$V_D = \text{constant, e.g. } 1V$$

These are the simplest models, next we will learn more accurate models.

Link

Razavi Electronics Circuits 1: lecture 29